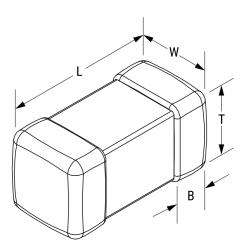


L1210R100MDWIT

Aliases (L1210R100MDWIT)

KEMET, L-DWI, Power, 10 uH, 20%



Click here for the 3D model.

| Dimensions | |
|------------|----------------|
| Chip Size | 1210 |
| L | 3.2mm +/-0.2mm |
| W | 2.5mm +/-0.2mm |
| Т | 2.5mm +/-0.2mm |
| LL | 0.6mm +/-0.3mm |
| В | 0.6mm +/-0.3mm |

| Packaging Specifications | |
|--------------------------|------|
| Packaging | T&R |
| Packaging Quantity | 1000 |

| General Information | |
|---------------------|------------------------|
| Series | L-DWI |
| Style | SMD Chip |
| Description | Surface Mount Inductor |
| Features | High Current Type |
| RoHS | Yes |

| Specifications | |
|----------------------------|---|
| Inductance | 10 uH (0.1 MHz) |
| Inductance Tolerance | 20% |
| Temperature Range | -40/+105°C |
| Current | 900 mAmps (Isat, 30% Drop In Inductance), 900 mAmps (Irms, 40C Rise By Self Heating) |
| DC Resistance | 0.133 Ohms |
| Self-Resonant Frequency | 23 MHz |

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

单击下面可查看定价,库存,交付和生命周期等信息

>>KEMET(基美)